Surface Mount Digital Step Attenuator DAT-15575A Series

75 Ω 0 to 15.5 dB, 0.5 dB Step 1MHz to 2.5 GHz

The Big Deal

- Wideband, operates up to 2.5 GHz
- Glitchless attenuation transitions
- High IP3, 52 dBm



CASE STYLE: DG983-2

Product Overview

The DAT-15575A+ series of 75 Ω digital step attenuators provides adjustable attenuation from 0 to 15.5 dB in 0.5 dB steps. The control is a 5-bit serial/parallel interface, and the attenuators operate with either single positive or dual (positive and negative) supply voltage. DAT-15575A+ series models are produced by a unique CMOS process on silicon, offering the performance of GaAs with the advantages of conventional CMOS devices.

Feature	Advantages
Wideband operation, specified from 1MHz to 2.5 GHz	Can be used in multiple applications such as various versions of DOCSIS, satellite and defense, reducing part count.
Serial or parallel interface	Models available with serial or parallel interface mode to suit customer demand.
Good VSWR, 1.3:1 typ.	Eases interfacing with adjacent components and results in low amplitude ripple.
Single positive supply models: (Model suffixes: -SP+ and –PP+) +2.3 to +3.6V+	Use of single positive supply simplifies power supply design. An internal negative voltage generator supplies the desired negative voltage. Single positive supply results in excellent spurious performance, -140 dBm typical.
Dual supply models: (Model suffixes: -SN+ and -PN+) +2.7 to +3.6V (Positive) and -3.6 to -3.2V (Negative)	Dual supply provides spurious-free operation. It also allows fast switching up to 1 MHz (vs. 25 kHz for single supply).
Useable over a wide range of supply volt- ages, +2.3/2.7 to 5.2V	Wide range fo positive operating voltages allows the DAT-15575A+ Series of models to be used in a wide range of applications. See Application Note AN-70-032 for operation above +3.6V
Footprint compatible to DAT-15575-XX+ Series (XX=SN/SP/PN/PP)	Can fit into existing footprint and provide wideband performance, to 2.5 GHz instead of 2.0 GHz.
Glitchless Attenuation Transitions, 0.26 typical	Compared to previous generation of digital attenuatiors which is a vast improvement.

Key Features

75Ω 1-2500 MHz

15.5 dB, 0.5 dB Step 5 Bit, Serial Control Interface, Dual Supply Voltages

Product Features

- Dual Supply (Positive & Negative) Voltages
- Immune to latch up
- Glitchless attenuation transitions
- Excellent accuracy, 0.1 dB Typ
- Serial control interface
- Low Insertion Loss
- High IP3, +55-69 dBm
- Excellent return loss, 18 dB typ.
- Very low DC power consumption
- Small size 4.0 x 4.0 mm

Typical Applications

- DOCSIS 3.1
- Portable Wireless
- Fiber CPE and infrastructure
- MMDS & Wireless LAN
- Satellite CPE and infrastructure
- UNII & Hiper LAN
- · Power amplifier distortion canceling loop



Generic photo used for illustration purposes only

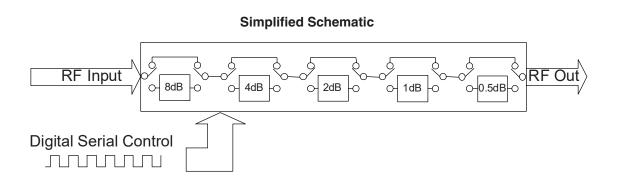
DAT-15575A-SN+

CASE STYLE: DG983-2

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

The DAT-15575A-SN+ is a 75Ω RF digital step attenuator that offers an attenuation range up to 15.5 dB in 0.5 dB steps. The control is a 5-bit serial interface, operating on dual (positive and negative) supply voltages. The DAT-15575A-SN+ is produced using a unique CMOS process on silicon, offering the performance of GaAs, with the advantages of conventional CMOS devices.



REV. OR M155582 DAT-15575A-SN+ RS/CP/AM 200513 Page 2 of 8



RF Electrical Specifications, 1-2500 MHz, T_{AMB}=25°C, V_{DD}=+3V, V_{SS}=-3.2V, 75Ω

Parameter	Freq. Range (GHz)	Min.	Тур.	Max.	Units	
	0.001-1.2		0.03	0.17		
Accuracy @ 0.5 dB Attenuation Setting	1.2-2.0	—	0.05	0.18	dB	
	2.0-2.5	_	0.1	0.19		
	0.001-1.2	—	0.03	0.18		
Accuracy @ 1 dB Attenuation Setting	1.2-2.0	_	0.1	0.20	dB	
	2.0-2.5	—	0.1	0.23		
	0.001-1.2	—	0.07	0.21		
Accuracy @ 2 dB Attenuation Setting	1.2-2.0	_	0.15	0.26	dB	
	2.0-2.5	—	0.15	0.31		
	0.001-1.2	—	0.05	0.27		
Accuracy @ 4 dB Attenuation Setting	1.2-2.0	_	0.15	0.36	dB	
	2.0-2.5	—	0.2	0.47		
	0.001-1.2	—	0.1	0.39		
Accuracy @ 8 dB Attenuation Setting	1.2-2.0	_	0.24	0.60	dB	
	2.0-2.5	_	0.35	0.79		
Insertion Loss ¹ @ all attenuator set to 0dB	0.001-1.2	—	1.2	1.8	dB	
insertion Loss. @ all attenuator set to 00B	1.2-2.5	_	1.6	1.9	uв	
VSWR	0.001-1.2	_	1.3	_	:1	
VSVIN	1.2-2.5	_	1.4	_	. 1	
Input IP3 (at Min. and Max. Attenuation)	.005-2.5	—	55-69	_	dBm	
Input IP2	.005-2.5		See Fig. 1		dBm	
Input Power @ 0.2dB Compression (at Min. and Max. Attenuation)	0.030-2.5	_	+30	-	dBm	
Input Operating Power	1 MHz to 30 MHz	_	_	See Fig. 2	dBm	
	>30 MHz		—	+24		
Thermal Resistance (Junction to case)	_	_	25	_	°C/W	

DC Electrical Specifications

Parameter	Min.	Тур.	Max.	Units
VDD, Supply Voltage	2.7	3	3.6 ²	V
IDD Supply Current	—	—	80	μA
Control Input Low	-0.3	—	0.6 ³	V
Vss, Supply Voltage	-3.6	—	-3.2	V
Iss, Supply Current	-40	—	—	μA
Control Input High	1.17	—	3.6	V
Control Current	—	—	20	μA

1. I. Loss values are de-embedded from test board Loss (test board's Insertion Loss: 0.10dB @100MHz, 0.40dB @1200MHz, 0.55dB @2000MHz, 0.75dB @4000MHz).

2. For operation above +3.6V see application note, AN-70-032

3. 0V during power-up.

Absolute Maximum Ratings⁴

Parameter		Ratings		
Operating Temp	erature	-40°C to 105°C		
Storage Tempera	ature	-65°C to 150°C		
VDD		-0.3V Min., 5.5V Max.		
Vss		-3.8V Min.		
Voltage on any i	nput	-0.3V Min., 3.6V Max.		
	1-30 MHz	Figure 2		
Input Power	30-2500MHz	+30dBm		

4. Permanent damage may occur if any of these limits are exceeded.

Switching Specifications

Parameter	Min.	Тур.	Max.	Units
Switching Speed, 50% Control to 0.5dB of Attenuation Value	° –	0.4	0.7	µSec
Switching Control Frequency	—	1.0	—	MHz

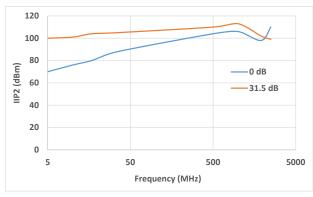


Figure 1. IP2 vs. frequency and attenuation

5. Operation between max operating and absolute max input power will result in reduced reliability.

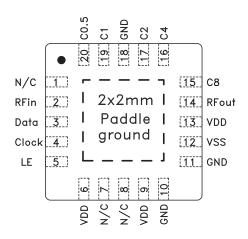


Pin Description

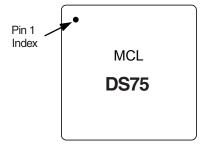
Function	Pin Number	Description		
N/C	1	Not connected (Note 8)		
RF in	2	RF in port (Note 1)		
Data	3	Serial Interface data input (Note 3)		
Clock	4	Serial Interface clock input		
LE	5	Latch Enable Input (Note 2)		
V _{DD}	6	Power Supply		
N/C	7	Not connected (Note 7)		
N/C	8	Not connected		
V _{DD}	9	Power Supply		
GND	10	Ground connection		
GND	11	Ground connection		
V _{ss}	12	Negative Supply Voltage		
V _{DD}	13	Power Supply		
RF out	14	RF out port (Note 1)		
C8	15	Control for attenuation bit, 8 dB (Note 4)		
C4	16	Control for attenuation bit, 4 dB (Note 4)		
C2	17	Control for attenuation bit, 2 dB (Note 4)		
GND	18	Ground Connection		
C1	19	Control for attenuation bit, 1 dB (Note 4)		
C0.5	20	Control for attenuation bit, 0.5 dB (Note 4, 7)		
GND	Paddle	Paddle ground (Note 5)		

DAT-15575A-SN+

Pin Configuration (Top View)



Device Marking



Notes:

1. Both RF ports must be held at 0VDC or DC blocked with an external series capacitor. RF in and RF out are interchageable.

2. Latch Enable (LE) has an internal 2M Ω pull-up resistor to V_{DD}.

3. Place a 10K Ω resistor in series to be compattible with previous generation of models. 10K Ω can be omiited in new designs.

4. Refer to Power-up Control Settings.

The exposed solder pad on the bottom of the package (See Pin configuration) must be grounded for proper device operation.

6. N/A

7. This pin has internal $1M\Omega$ short resistor to ground.

8. Place 10KΩ resistor to ground externally.

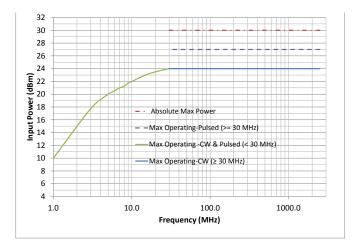
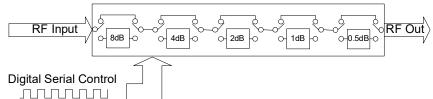


Figure 2. Max Input power vs. frequency. Pulsed Power: 5% duty cycle, 4620 μS period





Simplified Schematic



The DAT-15575A-SN+ Serial interface consists of 5 control bits that select the desired attenuation state, as shown in **Table 1**: Truth Table

Table 1. Truth Table								
Attenuation State	C8	C4	C2	C1	C0.5			
Reference	0	0	0	0	0			
0.5 (dB)	0	0	0	0	1			
1 (dB)	0	0	0	1	0			
2 (dB)	0	0	1	0	0			
4 (dB)	0	1	0	0	0			
8 (dB)	1	0	0	0	0			
15.5 (dB)	1	1	1	1	1			
Note: Not all 32	possible cor	nbinations of	of C0.5 - C8	are shown	in table			

The serial interface is a 5-bit serial in, parallel-out shift register buffered by a transparent latch.

It is controlled by three CMOS-compatible signals: Data, Clock, and Latch Enable (LE). The Data and Clock inputs allow data to be serially entered into the shift register, a process that is independent of the state of the LE input.

The LE input controls the latch. When LE is HIGH, the latch is transparent and the contents of the serial shift register control the attenuator. When LE is brought LOW, data in the shift register is latched.

The shift register should be loaded while LE is held LOW to prevent the attenuator value from changing as data is entered. The LE input should then be toggled HIGH and brought LOW again, latching the new data. The timing for this operation is defined by **Figure 3** (Serial Interface Timing Diagram) and **Table 2** (Serial Interface AC Characteristics).

Figure 3: Serial Interface Timing Diagram

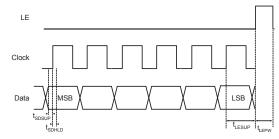
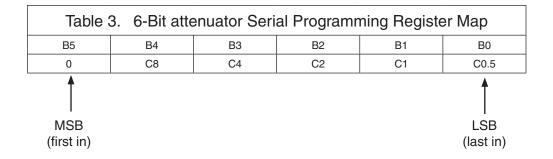


Table 2. Serial Interface AC Characteristics							
Symbol	Parameter	Min.	Max.	Units			
f _{clk}	Serial data clock frequency (Note 1)		10	MHz			
t _{clkH}	Serial clock HIGH time	30		ns			
t _{clkL}	Serial clock LOW time	30		ns			
t _{LESUP}	LE set-up time after last clock falling edge	10		ns			
t _{LEPW}	LE minimum pulse width	30		ns			
t _{SDSUP}	Serial data set-up time before clock rising edge	10		ns			
t _{sDHLD}	Serial data hold time after clock falling edge	10		ns			
	fied during the functional p functional pattern are clock						



The DAT-15575A-SN+, uses a common 5-bit serial word format, as shown in **Table 3**: 5-Bit attenuator Serial Programming Register Map.

The bit B4, corresponds to the 8-dB Step and the last bit, the LSB, corresponds to the 0.5 dB step.



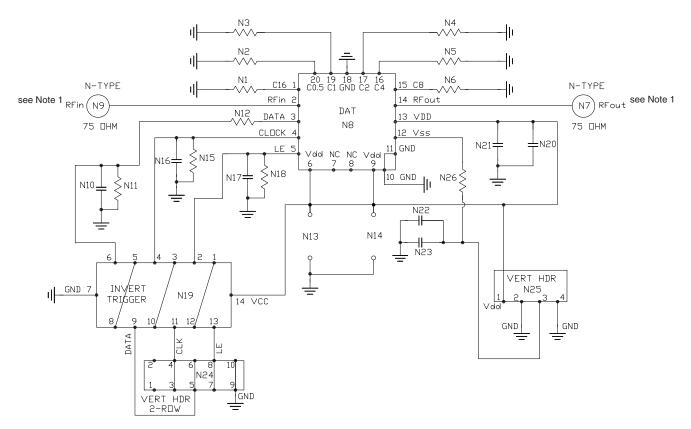
Power-up Control Settings

The DAT-15575A-SN+ always assumes a specifiable attenuation setting on power-up, allowing a known attenuation state to be established before an initial serial control word is provided.

When the attenuator powers up, the five control bits are set to whatever data is present on the six data inputs (C0.5 to C8).

This allows any one of the 32 attenuation settings to be specified as the power-up state.

TB-343 Evaluation Board Schematic Diagram



Note 1: Both RF ports must be held at 0VDC or DC blocked with an external series capacitor.



TB-343

Bill of Materials				
N1-N6, N11, N12, N15, N18	Resistor 0603 10 KOhm +/- 1%			
N10, N16, N17, N20	NPO Capacitor 0603 100pF +/- 5%			
N21	Tantalum Capacitor 0805 100nF +/- 10%			
N19	Hex Invert Schmitt Trigger MSL1			

**N12 can be reduced to 0 Ohms

Additional Detailed Technical Information

additional information is available on our dash board. To access this information click here

	Data Table
Performance Data	Swept Graphs
	S-Parameter (S2P Files) Data Set (.zip file)
Case Style	DG983-2 Plastic package, exposed paddle, lead finish: NiPdAu
Tape & Reel	F87
Standard quantities available on reel	7" reels with 20, 50, 100 or 200 devices 13" reels with 3K devices
Suggested Layout for PCB Design	PL-202
Evaluation Board	TB-343
Environmental Ratings	ENV33T1

ESD Rating

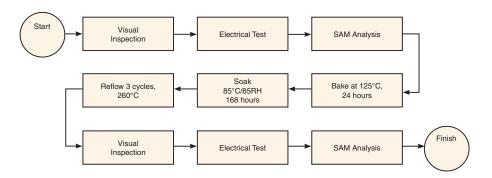
Human Body Model (HBM): Class 1C (1000 to <2000V) in accordance with MIL-STD-883 method 3015 (pass 1500V).

Charge Device Model (CDM): Class C3 (>1000V) per JESD22-C101F

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

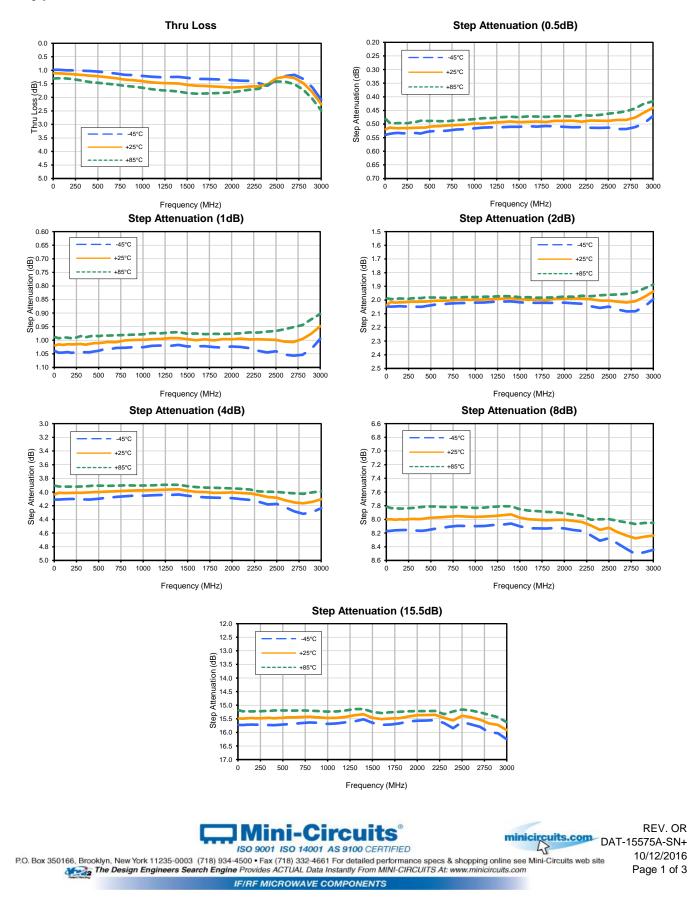
MSL Test Flow Chart



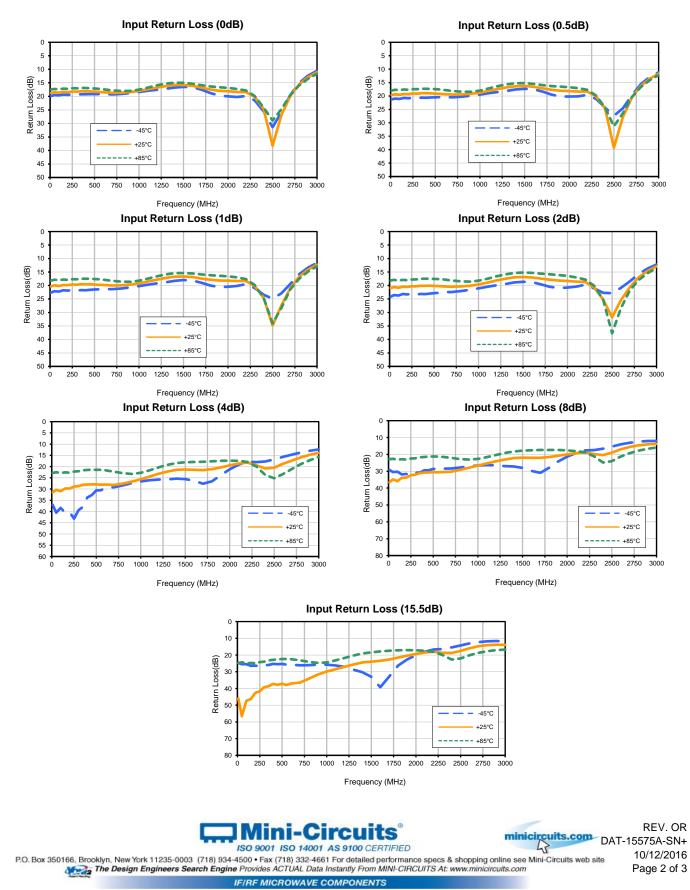
Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

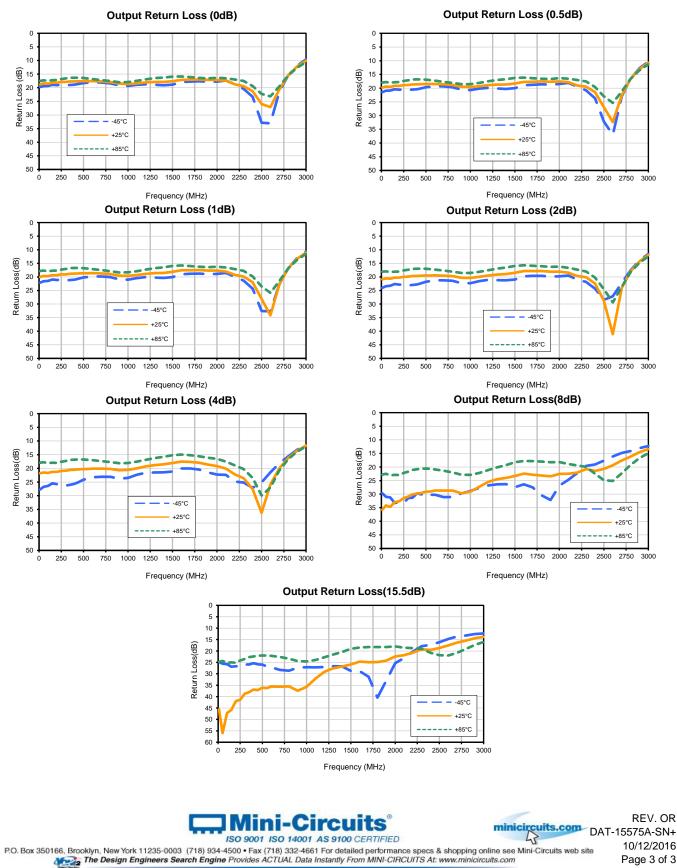
Typical Performance Curves



Typical Performance Curves



Typical Performance Curves

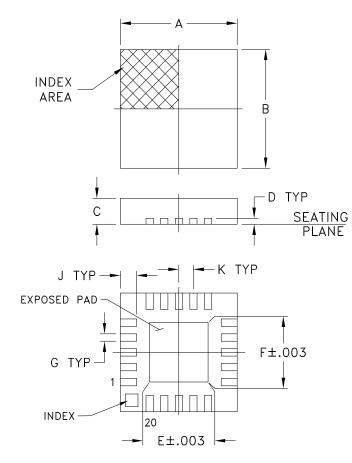


IF/RF MICROWAVE COMPONENTS

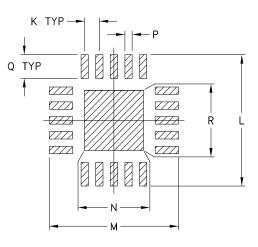
Case Style

DG983-2

Outline Dimensions



PCB Land Pattern



Suggested Layout, Tolerance to be within ±.002

CASE #	А	В	С	D	Е	F	G	Н	J	K
DG983-2	.157	.157	.033	.008	.085	.085	.009		.022	.020
DG985-2	(4.00)	(4.00)	(0.85)	(0.20)	(2.15)	(2.15)	(0.23)		(0.55)	(0.50)

CASE #	L	М	Ν	Р	Q	R	WT. GRAM
DG983-2	.177 (4.50)	.177 (4.50)	.081 (2.06)	.010 (0.25)	.032 (0.81)	.081 (2.06)	.04

Dimensions are in inches (mm). Tolerances: 2 Pl. <u>+</u>.01; 3 Pl. <u>+</u>.005

Notes:

- 1. Case material: Plastic.
- 2. Termination finish:

For RoHS Case Styles: 0.2 µinches of Gold (Au) over 0.1 µinched of Palladium (Pd) over 10 µinches of Nickel (Ni). All models, (+) suffix.

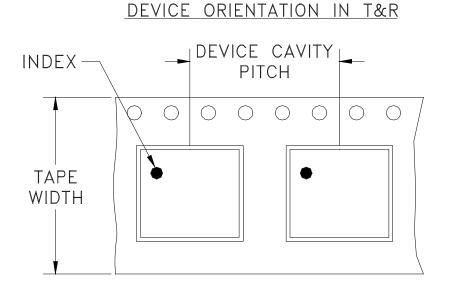
For RoHS-5 Case Styles: Tin-Lead plate. All models, no (+) suffix.





P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For detailed performance specs & shopping online see Mini-Circuits web site The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com RF/IF MICROWAVE COMPONENTS

Tape & Reel Packaging TR-F87



DIRECTION OF FEED

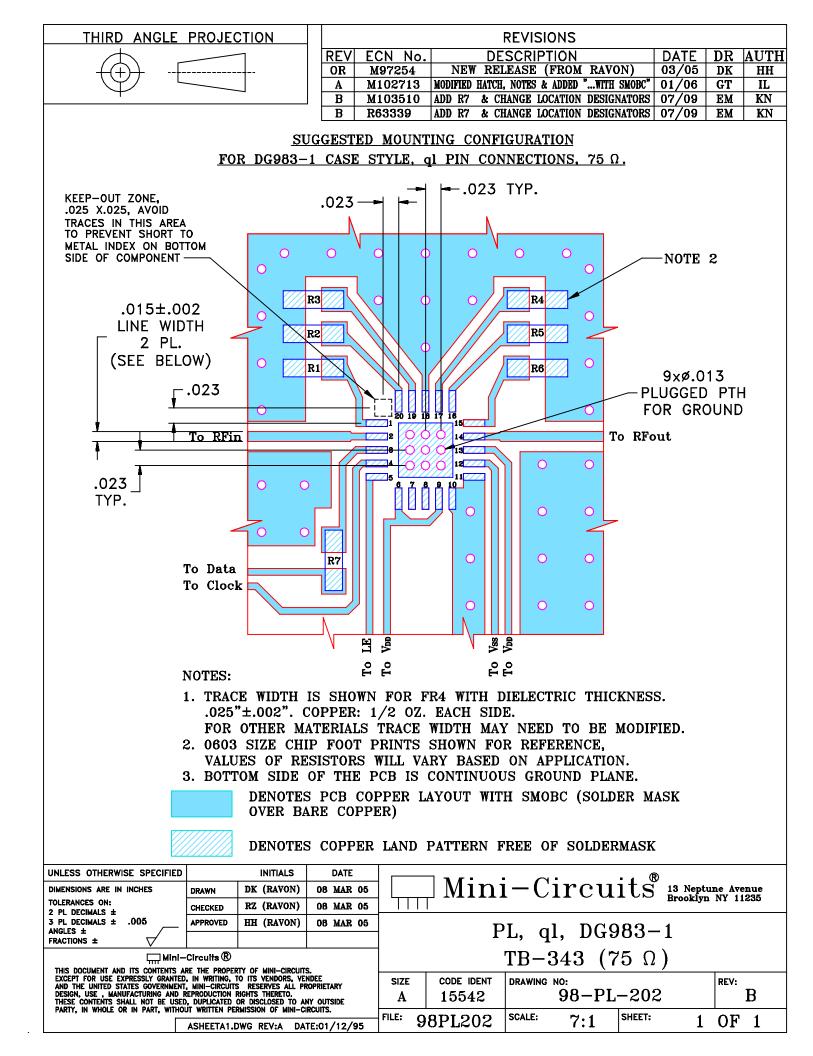
Tape Width, mm	Device Cavity Pitch, mm	Reel Size, inches	Devices per Reel	
12	8	7	Small quantity standards (see note)	20 50 100 200 500 1000
		13	Standard	3000

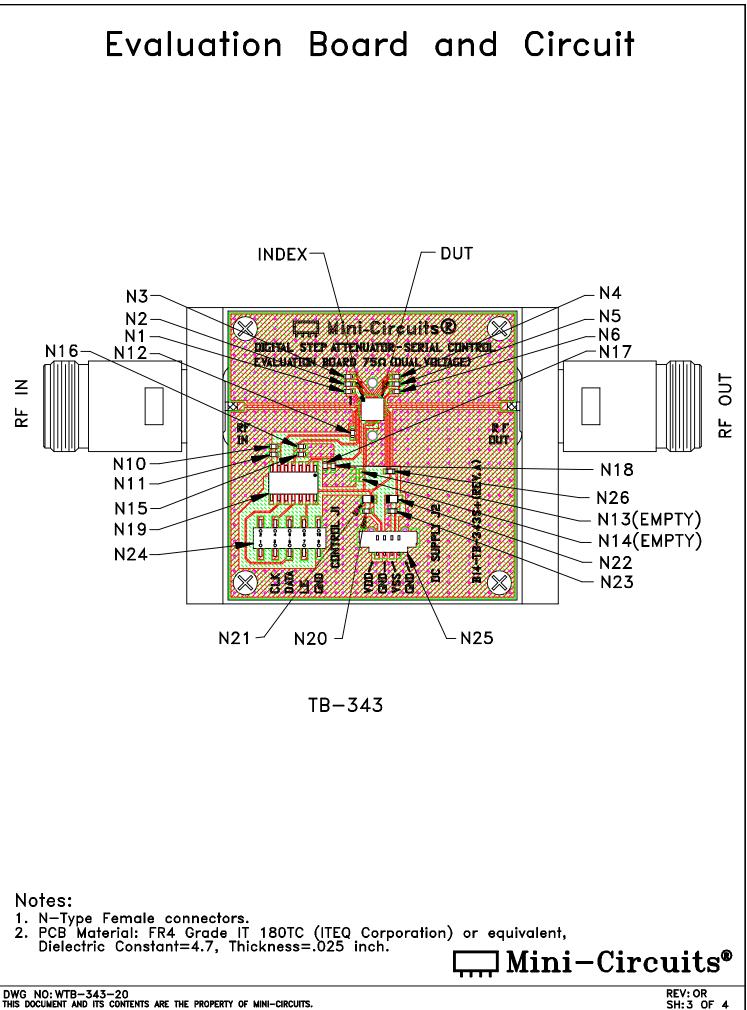
Note : Please Consult individual model data sheet to determine device per reel availability

Mini-Circuits carrier tape materials provide protection from ESD (Electro-Static Discharge) during handling and transportation. Tapes are static dissipative and comply with industry standards EIA-481/EIA-541.

Go to: www.minicircuits.com/pages/pdfs/tape.pdf







Mini-Circuits

ENV33T1

All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec	
Operating Temperature	-40° to 85° C or -40° to 105° C Ambient Environment	Refer to Individual Model Data Sheet	
Storage Temperature	-55° to 100° C or -65° to 150° C Ambient Environment	Refer to Individual Model Data Sheet	
Temperature Humidity Bias	85°C, 85% RH, 96 hours	JESD22-A101B	
Thermal Shock	-55° to 100°C, 100 cycles	MIL-STD-202, Method 107, Condition A-3, except +100°C	
Solder Reflow Heat	Pb-Free Process: 260°C peak	J-STD-020, Table 4-1, 4-2 and 5-2; Figure 5-1	
Solderability	10X magnification, 95% coverage	rage JESD22-B102, Method 1: Dip and Look Test	
Marking Resistance to Solvents	Laser marked, visual observation	Mini-Circuits D4-Q4T0-04	

ENV33T1 Rev: B 10/01/14 M148446 File: ENV33T1.pdf

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